

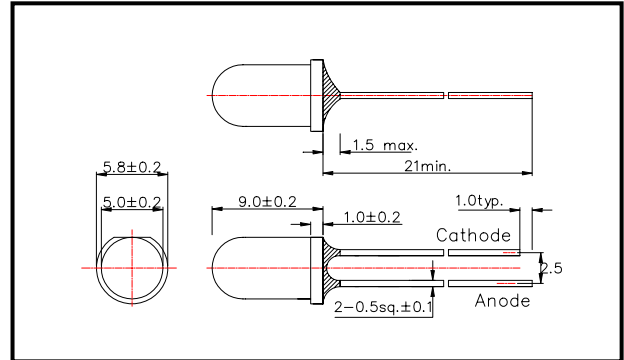
# L940-01T Infrared LED Lamp

L940-01T is an AlGaAs LED mounted on a lead frame with a clear epoxy lens and is 34mW typical of output power at 940nm.

### ◆ Specifications

1) Product Name	Infrared LED Lamp
2) Type No.	L940-01T
3) Chip	
(1) Chip Material	AlGaAs
(2) Peak Wavelength	940nm typ.
4) Package	
(1) Type	Φ5mm clear molding
(2) Resin Material	Epoxy Resin
(3) Lead Frame	Soldered(Lead Free)

### ◆ Outer dimension (Unit: mm)



### ◆ Absolute Maximum Ratings

Item	Symbol	Maximum Rated Value	Unit	Ambient Temperature
Power Dissipation	P <sub>D</sub>	160	mW	T <sub>a</sub> =25°C
Forward Current	I <sub>F</sub>	100	mA	T <sub>a</sub> =25°C
Pulse Forward Current	I <sub>FP</sub>	1000	mA	T <sub>a</sub> =25°C
Reverse Voltage	V <sub>R</sub>	5	V	T <sub>a</sub> =25°C
Junction Temperature	T <sub>J</sub>	100		
Thermal Resistance	R <sub>thjp</sub>	290		
Operating Temperature	T <sub>OPR</sub>	-30 ~ +85	°C	
Storage Temperature	T <sub>STG</sub>	-30 ~ +100	°C	
Soldering Temperature	T <sub>SOL</sub>	265	°C	

‡Pulse Forward Current condition: Duty=1% and Pulse Width=10us.

‡Soldering condition: Soldering condition must be completed within 3 seconds at 265°C

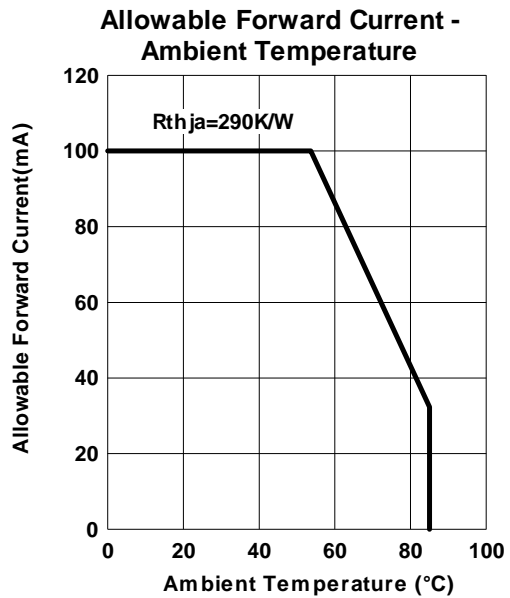
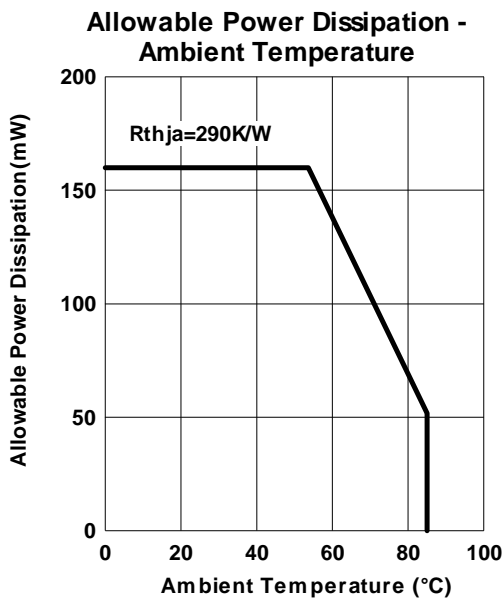
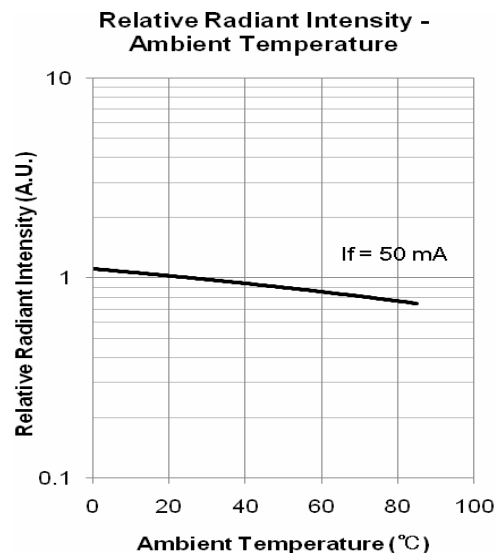
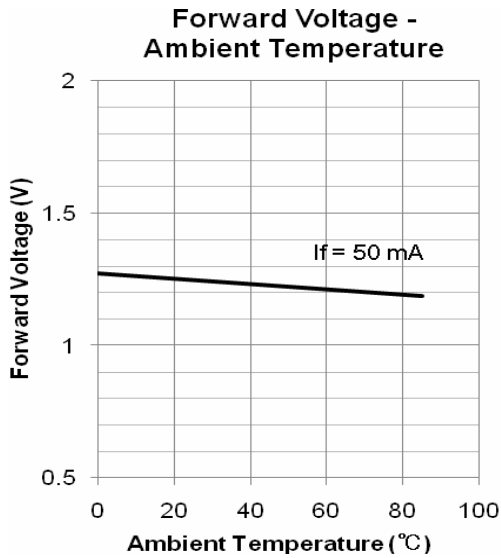
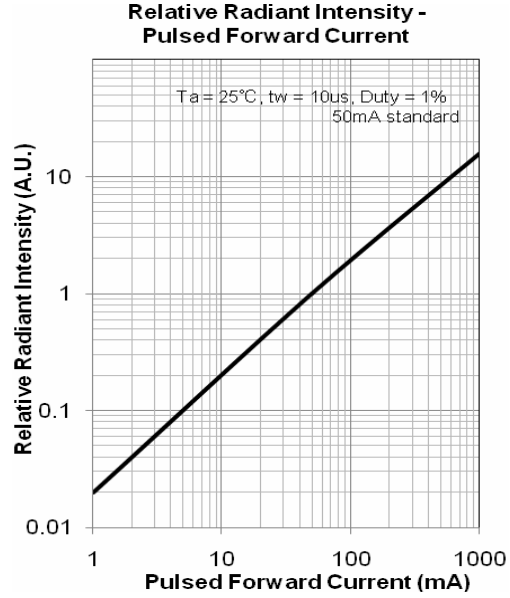
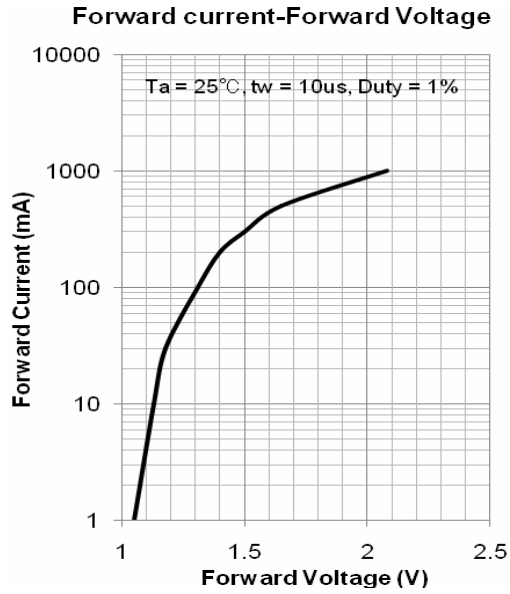
‡Thermal resistance: junction – ambient, leads 7mm, soldered on PCB.

### ◆ Electro-Optical Characteristics [T<sub>a</sub>=25°C]

Item	Symbol	Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =50mA DC		1.25	1.40	V
		I <sub>F</sub> =100mA, t <sub>p</sub> =20ms		1.35	1.55	
Reverse Current	I <sub>R</sub>	V <sub>R</sub> =5V			10	uA
Total Radiated Power	P <sub>O</sub>	I <sub>F</sub> =50mA DC	13.0	17.0		mW
		I <sub>F</sub> =100mA, t <sub>p</sub> =20ms		34.0		
Radiant Intensity	I <sub>E</sub>	I <sub>F</sub> =50mA DC		60		mW/sr
		I <sub>F</sub> =100mA, t <sub>p</sub> =20ms		120		
Peak Wavelength	λ <sub>P</sub>	I <sub>F</sub> =50mA DC	930	940	955	nm
Half Width	Δλ	I <sub>F</sub> =50mA DC		50		nm
Viewing Half Angle	θ <sub>1/2</sub>	I <sub>F</sub> =50mA DC		±11		deg.
Rise Time	t <sub>r</sub>	I <sub>F</sub> =50mA DC		1000		ns
Fall Time	t <sub>f</sub>	I <sub>F</sub> =50mA DC		500		ns

‡Total Radiated Power is measured by Photodyne #500

‡Radiant Intensity is measured by Tektronix J-6512



Lead ( Pb ) Free Product – RoHS Compliant

